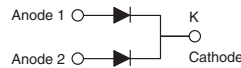
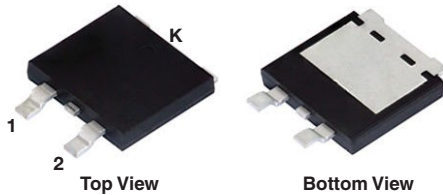


Dual Low-Voltage TMBS[®] (Trench MOS Barrier Schottky) Rectifier

 Ultra Low $V_F = 0.30\text{ V}$ at $I_F = 5.0\text{ A}$

eSMP[®] Series SMPD (TO-263AC)



DESIGN SUPPORT TOOLS AVAILABLE



| PRIMARY CHARACTERISTICS | |
|------------------------------|-----------------|
| $I_{F(AV)}$ | 2 x 15 A |
| V_{RRM} | 45 V |
| I_{FSM} | 200 A |
| V_F at $I_F = 15\text{ A}$ | 0.40 V |
| T_J max. | 150 °C |
| Package | SMPD (TO-263AC) |
| Circuit configuration | Common cathode |

FEATURES

- Trench MOS Schottky technology
- Very low profile - typical height of 1.7 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available
 - Automotive ordering code; base P/NHM3
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


RoHS
COMPLIANT
HALOGEN
FREE

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating
Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Base P/NHM3_X - halogen-free, RoHS-compliant, and AEC-Q101 qualified

("_X" denotes revision code e.g. A, B,.....)

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

| MAXIMUM RATINGS ($T_A = 25\text{ °C}$ unless otherwise noted) | | | |
|-----------------------------------------------------------------------------------|----------------|-------------|------|
| PARAMETER | SYMBOL | V30D45C | UNIT |
| Maximum repetitive peak reverse voltage | V_{RRM} | 45 | V |
| Maximum average forward rectified current (fig. 1) | $I_{F(AV)}$ | per device | 30 |
| | | per diode | 15 |
| Peak forward surge current 10 ms single half sine-wave superimposed on rated load | I_{FSM} | 200 | A |
| Operating junction and storage temperature range | T_J, T_{STG} | -40 to +150 | °C |

| ELECTRICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted) | | | | | | | |
|----------------------------------------------------------------------------------------------|-----------------------------------|-----------------------------------|-------------|----------------------|------|---------------|------|
| PARAMETER | TEST CONDITIONS | | SYMBOL | TYP. | MAX. | UNIT | |
| Instantaneous forward voltage per diode | $I_F = 5.0\text{ A}$ | $T_A = 25\text{ }^\circ\text{C}$ | $V_F^{(1)}$ | 0.42 | - | V | |
| | | | | $I_F = 7.5\text{ A}$ | 0.44 | | - |
| | | | | $I_F = 15\text{ A}$ | 0.49 | | 0.57 |
| | $T_A = 125\text{ }^\circ\text{C}$ | $I_F = 5.0\text{ A}$ | | 0.30 | - | | |
| | | $I_F = 7.5\text{ A}$ | | 0.33 | - | | |
| | | $I_F = 15\text{ A}$ | | 0.40 | 0.48 | | |
| Reverse current per diode | $V_R = 45\text{ V}$ | $T_A = 25\text{ }^\circ\text{C}$ | $I_R^{(2)}$ | - | 1500 | μA | |
| | | $T_A = 125\text{ }^\circ\text{C}$ | | 12 | 50 | mA | |

Notes

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
 (2) Pulse test: pulse width $\leq 5\text{ ms}$

| THERMAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted) | | | | |
|-------------------------------------------------------------------------------------------|------------|--------------------------|---------|--------------------|
| PARAMETER | | SYMBOL | V30D45C | UNIT |
| Typical thermal resistance | per diode | $R_{\theta JC}$ | 1.6 | $^\circ\text{C/W}$ |
| | per device | | 0.9 | |
| | per device | $R_{\theta JA}^{(1)(2)}$ | 45 | |

Notes

- (1) The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$
 (2) Free air, without heatsink

| ORDERING INFORMATION (Example) | | | | |
|---------------------------------------|-----------------|------------------------|---------------|------------------------------------|
| PREFERRED P/N | UNIT WEIGHT (g) | PREFERRED PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |
| V30D45C-M3/I | 0.55 | I | 2000/reel | 13" diameter plastic tape and reel |
| V30D45CHM3_A/I ⁽¹⁾ | 0.55 | I | 2000/reel | 13" diameter plastic tape and reel |

Note

- (1) AEC-Q101 qualified

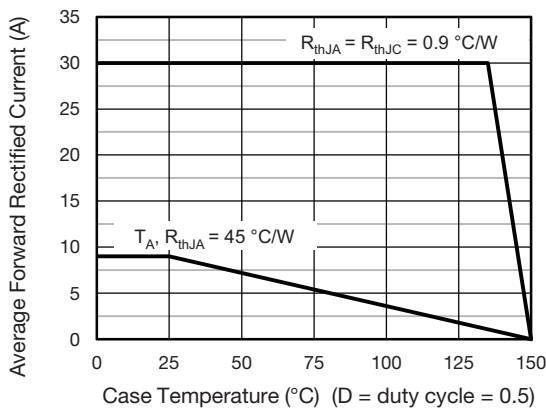
RATINGS AND CHARACTERISTICS CURVES ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)


Fig. 1 - Forward Current Derating Curve

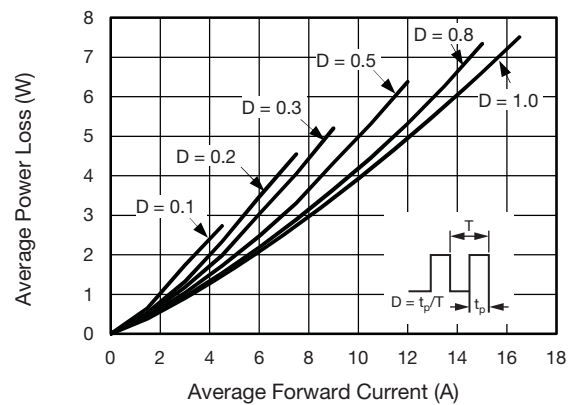


Fig. 2 - Forward Power Loss Characteristics Per Diode

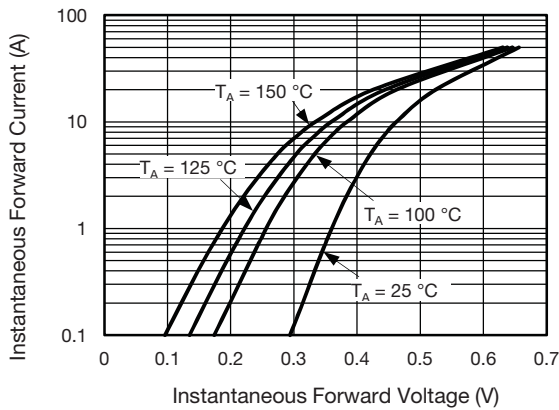


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

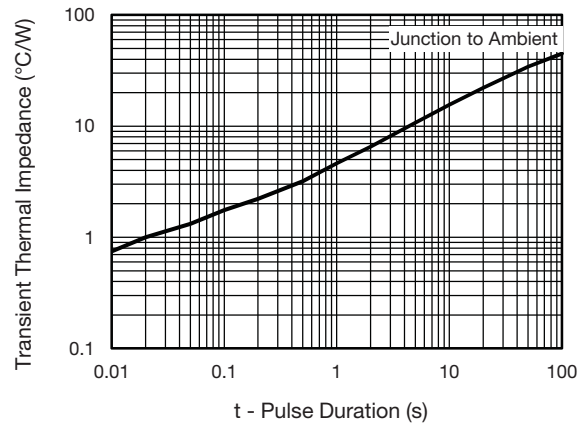


Fig. 6 - Typical Transient Thermal Impedance Per Diode

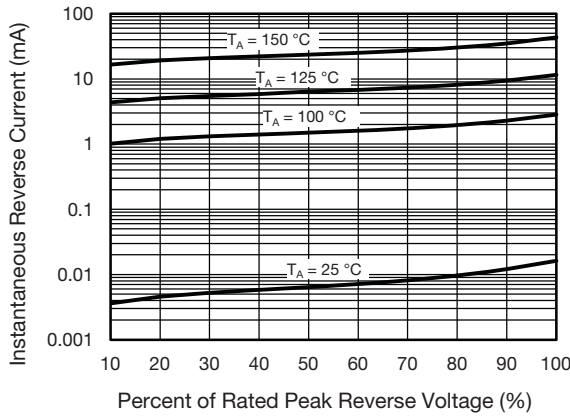


Fig. 4 - Typical Reverse Characteristics Per Diode

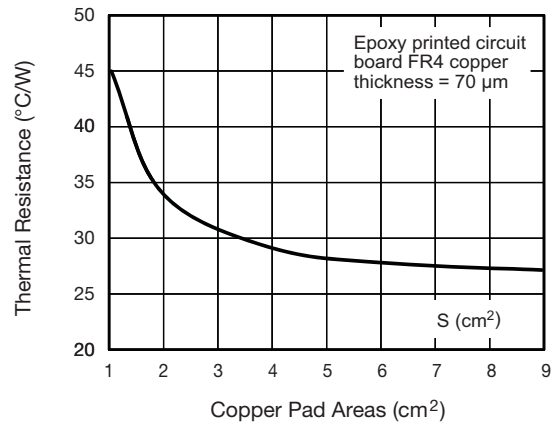


Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas

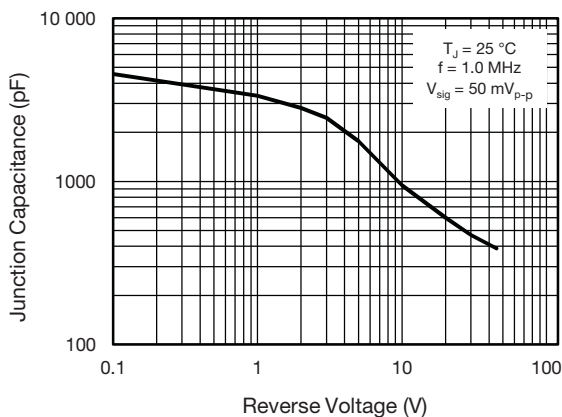
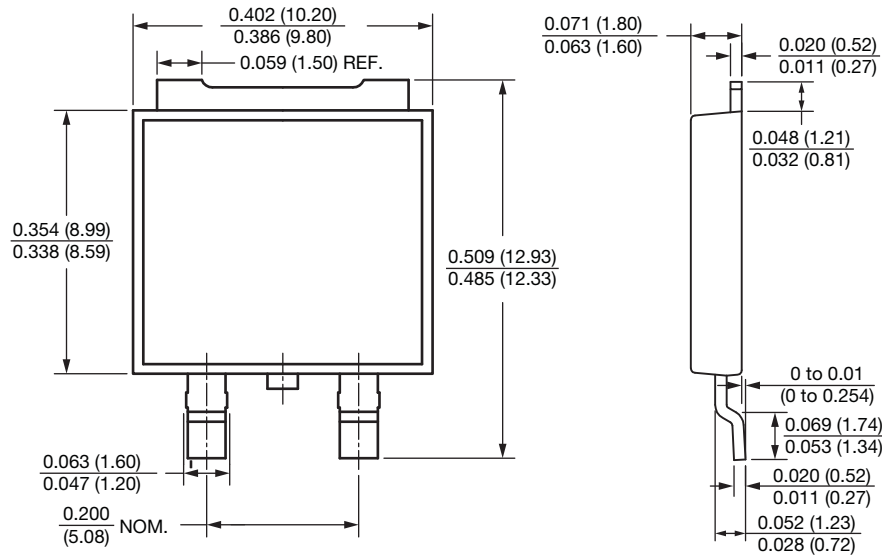


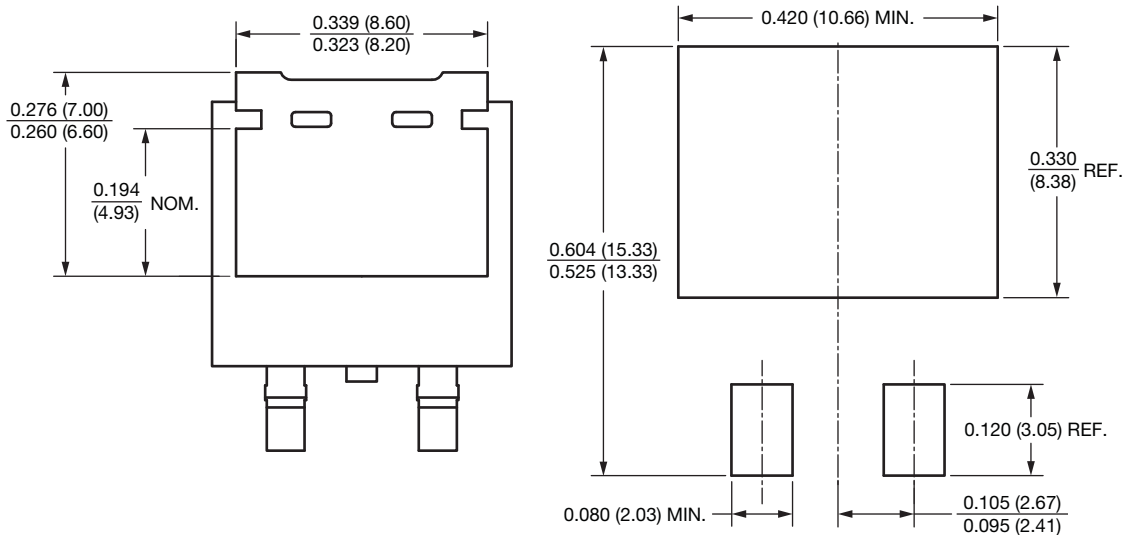
Fig. 5 - Typical Junction Capacitance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

SMPD (TO-263AC)



Mounting Pad Layout





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